

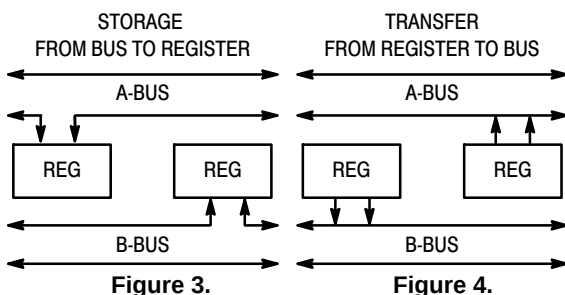
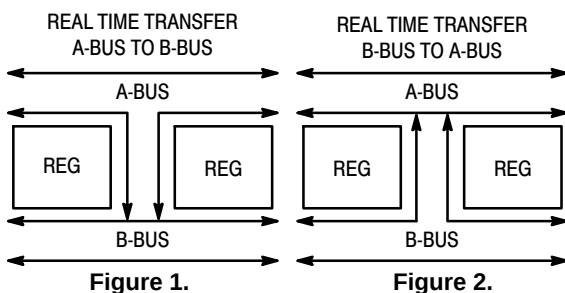
MC74AC646, MC74ACT646

Octal Transceiver/Register with 3-State Outputs (Non-inverting)

The MC74AC646/74ACT646 consist of registered bus transceiver circuits, with outputs, D-type flip-flops and control circuitry providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Data on the A or B bus will be loaded into the respective registers on the LOW-to-HIGH transition of the appropriate clock pin (CAB or CBA). The four fundamental data handling functions available are illustrated Figures 1 to 4.

Features

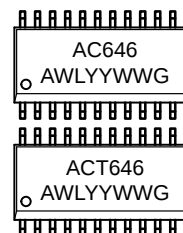
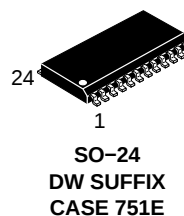
- Independent Registers for A and B Buses
- Multiplexed Real-Time and Stored Data Transfers
- Choice of True and Inverting Data Paths
- 3-State Outputs
- 300 mil Slim Dual In-Line Package
- Outputs Source/Sink 24 mA
- 'ACT646 Has TTL Compatible Inputs
- These are Pb-Free Devices



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MARKING DIAGRAMS



A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

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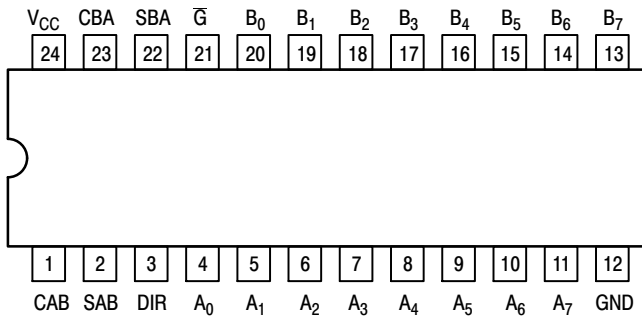


Figure 5. Pinout: 24-Lead Packages Conductors
(Top View)

PIN ASSIGNMENT

PIN	FUNCTION
A ₀ –A ₇	Data Register Inputs Data Register A Outputs
B ₀ –B ₇	Data Register B Inputs Data Register B Outputs
CAB, CBA	Clock Pulse Inputs
SAB, SBA	Transmit/Receive Inputs
DIR, $\overline{G}$	Output Enable Inputs

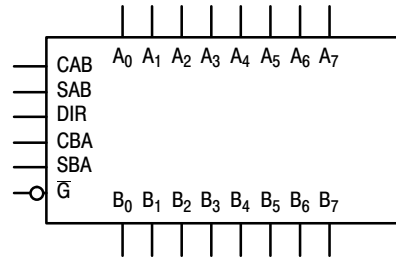
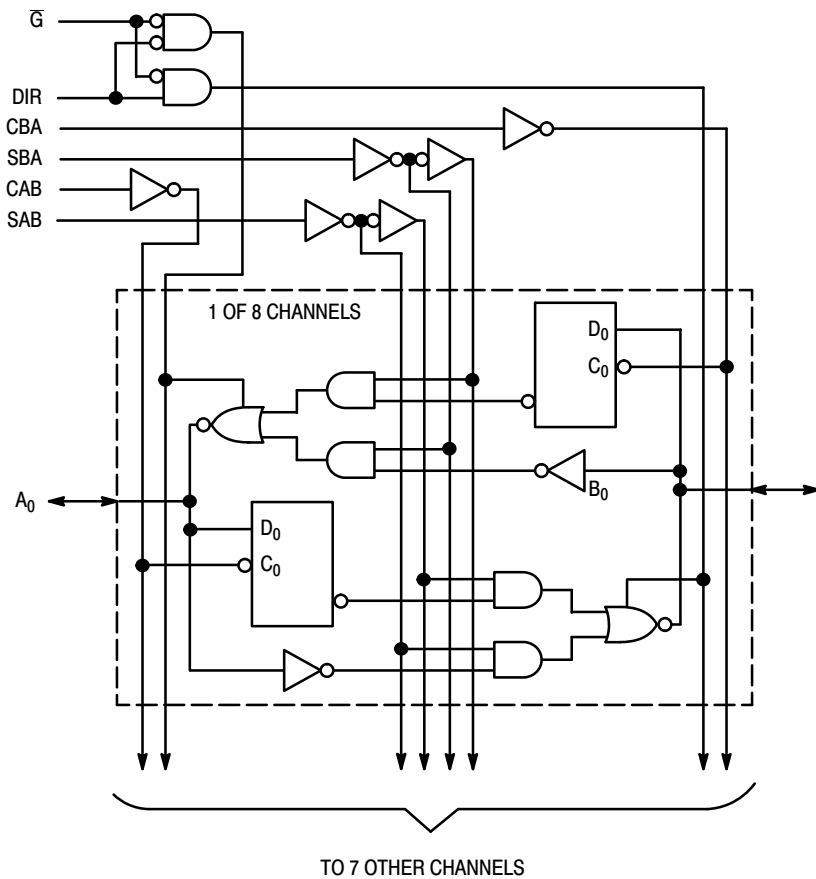


Figure 6. Logic Symbol



NOTE: This diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Figure 7. Logic Diagram

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FUNCTION TABLE

Inputs						Data I/O*		Operation or Function
$\overline{G}$	DIR	CAB	CBA	SAB	SBA	A ₀ -A ₇	B ₀ -B ₇	
H	X	H or L	H or L	X	X	Input	Input	Isolation
H	X	$\downarrow$	$\downarrow$	X	X			Store A and B Data
L	L	X	X	X	L	Output	Input	Real Time B Data to A Bus
L	L	X	X	X	H			Stored B Data to A Bus
L	H	X	X	L	X	Input	Output	Real Time A Data to B Bus
L	H	H or L	X	H	X			Stored A Data to B Bus

*The data output functions may be enabled or disabled by various signals at the $\overline{G}$ and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the appropriate clock inputs.

NOTE: H = HIGH Voltage Level; L = LOW Voltage Level; X = Immaterial; $\downarrow$ = LOW-to-HIGH Transition

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MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	−0.5 to +7.0	V
V _{IN}	DC Input Voltage (Referenced to GND)	−0.5 to V _{CC} +0.5	V
V _{OUT}	DC Output Voltage (Referenced to GND) (Note 1)	−0.5 to V _{CC} +0.5	V
I _{IK}	DC Input Diode Current	±20	mA
I _{OK}	DC Output Diode Current	±50	mA
I _{OUT}	DC Output Sink/Source Current	±50	mA
I _{CC}	DC Supply Current, per Output Pin	±50	mA
I _{GND}	DC Ground Current, per Output Pin	±100	mA
T _{STG}	Storage Temperature Range	− 65 to + 150	°C
T _L	Lead temperature, 1 mm from Case for 10 Seconds	260	°C
T _J	Junction Temperature Under Bias	140	°C
θ _{JA}	Thermal Resistance (Note 2)	59.8	°C/W
MSL	Moisture Sensitivity	Level 1	
F _R	Flammability Rating	Oxygen Index: 30% – 35% UL 94 V−0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage	Human Body Model (Note 3) Machine Model (Note 4) Charged Device Model (Note 5)	> 2000 > 200 > 1000
I _{Latchup}	Latchup Performance	Above V _{CC} and Below GND at 85°C (Note 6)	±100 mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I_{OUT} absolute maximum rating must be observed.
2. The package thermal impedance is calculated in accordance with JESD 51-7.
3. Tested to EIA/JESD22-A114-A.
4. Tested to EIA/JESD22-A115-A.
5. Tested to JESD22-C101-A.
6. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Typ	Max	Unit
V_{CC}	Supply Voltage	'AC	2.0	5.0	V
		'ACT	4.5	5.0	
V_{in}, V_{out}	DC Input Voltage, Output Voltage (Ref. to GND)	0	–	V_{CC}	V
t_r, t_f	Input Rise and Fall Time (Note 1) 'AC Devices except Schmitt Inputs	$V_{CC} @ 3.0 V$	–	150	ns/V
		$V_{CC} @ 4.5 V$	–	40	
		$V_{CC} @ 5.5 V$	–	25	
t_r, t_f	Input Rise and Fall Time (Note 2) 'ACT Devices except Schmitt Inputs	$V_{CC} @ 4.5 V$	–	10	ns/V
		$V_{CC} @ 5.5 V$	–	8.0	
T_A	Operating Ambient Temperature Range	-40	25	85	°C
I_{OH}	Output Current – High	–	–	-24	mA
I_{OL}	Output Current – Low	–	–	24	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. V_{in} from 30% to 70% V_{CC} ; see individual Data Sheets for devices that differ from the typical input rise and fall times.
2. V_{in} from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

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DC CHARACTERISTICS

Symbol	Parameter	V _{CC} (V)	74AC		74AC	Unit	Conditions
			T _A = +25°C		T _A = -40°C to +85°C		
			Typ	Guaranteed Limits			
V _{IH}	Minimum High Level Input Voltage	3.0	1.5	2.1	2.1	V	V _{OUT} = 0.1 V or V _{CC} - 0.1 V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V _{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.9	0.9	V	V _{OUT} = 0.1 V or V _{CC} - 0.1 V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V _{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I _{OUT} = -50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
		3.0	-	2.56	2.46	V	*V _{IN} = V _{IL} or V _{IH} -12 mA I _{OH} -24 mA -24 mA
		4.5	-	3.86	3.76		
		5.5	-	4.86	4.76		
V _{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I _{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
		3.0	-	0.36	0.44	V	*V _{IN} = V _{IL} or V _{IH} 12 mA I _{OL} 24 mA 24 mA
		4.5	-	0.36	0.44		
		5.5	-	0.36	0.44		
I _{IN}	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μA	V _I = V _{CC} , GND
I _{OZT}	Maximum 3-State Current	5.5	-	±0.6	±6.0	μA	V _I (OE) = V _{IL} , V _{IH} V _I = V _{CC} , GND V _O = V _{CC} , GND
I _{OLD}	†Minimum Dynamic Output Current	5.5	-	-	75	mA	V _{OLD} = 1.65 V Max
I _{OHD}		5.5	-	-	-75	mA	V _{OHD} = 3.85 V Min
I _{CC}	Maximum Quiescent Supply Current	5.5	-	8.0	80	μA	V _{IN} = V _{CC} or GND

*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

NOTE: I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC}.

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AC CHARACTERISTICS (For Figures and Waveforms – See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

Symbol	Parameter	V _{CC} * (V)	74AC			74AC		Unit	Fig. No.
			T _A = +25°C C _L = 50 pF			T _A = -40°C to +85°C C _L = 50 pF			
			Min	Typ	Max	Min	Max		
t _{PLH}	Propagation Delay Clock to Bus	3.3 5.0	4.0 2.5	10.5 7.5	16.5 12	3.0 2.0	18.5 13	ns	3-6
t _{PHL}	Propagation Delay Clock to Bus	3.3 5.0	3.0 2.0	9.5 6.5	14.5 10.5	2.5 1.5	16 11.5	ns	3-6
t _{PLH}	Propagation Delay Bus to Bus	3.3 5.0	2.5 1.5	7.5 5.0	12 8.0	2.0 1.0	13.5 9.0	ns	3-5
t _{PHL}	Propagation Delay Bus to Bus	3.3 5.0	1.5 1.5	7.5 5.0	12.5 9.0	1.5 1.0	13.5 9.5	ns	3-5
t _{PLH}	Propagation Delay SBA or SAB to A _n or B _n (w/A _n or B _n HIGH or LOW)	3.3 5.0	2.0 1.5	8.5 6.0	13.5 10	1.5 1.5	15.5 11	ns	3-6
t _{PHL}	Propagation Delay SBA or SAB to A _n or B _n (w/A _n or B _n HIGH or LOW)	3.3 5.0	1.5 1.5	8.5 6.0	13.5 10	1.5 1.5	15 11	ns	3-6
t _{PZH}	Enable Time G̅ to A _n or B _n	3.3 5.0	2.5 1.5	7.0 5.0	11.5 8.5	2.0 1.5	12.5 9.0	ns	3-7
t _{PZL}	Enable Time G̅ to A _n or B _n	3.3 5.0	2.5 1.5	7.5 5.5	12.5 9.0	2.0 1.5	14 10	ns	3-8
t _{PHZ}	Disable Time G̅ to A _n or B _n	3.3 5.0	3.0 2.0	8.0 6.5	12.5 10	2.5 2.0	13.5 11	ns	3-7
t _{PLZ}	Disable Time G̅ to A _n or B _n	3.3 5.0	2.0 1.5	7.5 6.0	12 9.5	2.0 1.5	13.5 10.5	ns	3-8
t _{PZH}	Enable Time DIR to A _n or B _n	3.3 5.0	2.0 1.5	6.5 5.0	11 7.5	1.5 1.0	12 8.5	ns	3-7
t _{PZL}	Enable Time DIR to A _n or B _n	3.3 5.0	2.5 1.5	7.0 5.0	11.5 8.0	2.0 1.0	13 9.0	ns	3-8
t _{PHZ}	Disable Time DIR to A _n or B _n	3.3 5.0	2.5 1.5	7.5 5.5	11.5 9.5	1.5 1.5	12.5 10	ns	3-7
t _{PLZ}	Disable Time DIR to A _n or B _n	3.3 5.0	1.5 1.5	7.5 5.5	12 9.5	1.5 1.5	13.5 10.5	ns	3-8

*Voltage Range 3.3 V is 3.3 V ±0.3 V.
Voltage Range 5.0 V is 5.0 V ±0.5 V.

MC74AC646, MC74ACT646

AC OPERATING REQUIREMENTS

Symbol	Parameter	V _{CC} * (V)	74AC		74AC	Unit	Fig. No.
			T _A = +25°C C _L = 50 pF		T _A = -40°C to +85°C C _L = 50 pF		
			Typ	Guaranteed Minimum			
t _s	Setup Time, HIGH or LOW Bus to Clock	3.3	2.0	5.0	5.5	ns	3-9
		5.0	1.5	4.0	4.5		
t _h	Hold Time, HIGH or LOW Bus to Clock	3.3	-1.5	0	0	ns	3-9
		5.0	-0.5	0.5	1.0		
t _w	Clock Pulse Width HIGH or LOW	3.3	2.0	3.5	4.5	ns	3-6
		5.0	2.0	3.5	3.5		

*Voltage Range 3.3 V is 3.3 V ±0.3 V.
Voltage Range 5.0 V is 5.0 V ±0.5 V.

DC CHARACTERISTICS

Symbol	Parameter	V _{CC} (V)	74ACT		74ACT	Unit	Conditions
			T _A = +25°C		T _A = -40°C to +85°C		
			Typ	Guaranteed Limits			
V _{IH}	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V _{OUT} = 0.1 V or V _{CC} - 0.1 V
V _{IL}	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V _{OUT} = 0.1 V or V _{CC} - 0.1 V
V _{OH}	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I _{OUT} = -50 μA
		4.5 5.5	- -	3.86 4.86	3.76 4.76	V	*V _{IN} = V _{IL} or V _{IH} -24 mA I _{OH} -24 mA
V _{OL}	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I _{OUT} = 50 μA
		4.5 5.5	- -	0.36 0.36	0.44 0.44	V	*V _{IN} = V _{IL} or V _{IH} 24 mA I _{OL} 24 mA
I _{IN}	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μA	V _I = V _{CC} , GND
ΔI _{CCT}	Additional Max. I _{CC} /Input	5.5	0.6	-	1.5	mA	V _I = V _{CC} - 2.1 V
I _{OZT}	Maximum 3-State Current	5.5	-	±0.6	±6.0	μA	V _I (OE) = V _{IL} , V _{IH} V _I = V _{CC} , GND V _O = V _{CC} , GND
I _{OLD}	†Minimum Dynamic Output Current	5.5	-	-	75	mA	V _{OLD} = 1.65 V Max
I _{OHD}		5.5	-	-	-75	mA	V _{OHD} = 3.85 V Min
I _{CC}	Maximum Quiescent Supply Current	5.5	-	8.0	80	μA	V _{IN} = V _{CC} or GND

*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

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AC CHARACTERISTICS (For Figures and Waveforms – See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

Symbol	Parameter	V _{CC} * (V)	74ACT			74ACT		Unit	Fig. No.
			T _A = +25°C C _L = 50 pF			T _A = -40°C to +85°C C _L = 50 pF			
			Min	Typ	Max	Min	Max		
t _{PLH}	Propagation Delay Clock to Bus	5.0	3.5	12.0	14.5	3.0	16.0	ns	3-6
t _{PHL}	Propagation Delay Clock to Bus	5.0	4.0	12.0	14.5	3.5	16.0	ns	3-6
t _{PLH}	Propagation Delay Bus to Bus	5.0	3.0	8.5	11.0	2.5	12.0	ns	3-5
t _{PHL}	Propagation Delay Bus to Bus	5.0	2.5	8.5	11.0	2.0	12.0	ns	3-5
t _{PLH}	Propagation Delay SBA or SAB to A _n or B _n (w/A _n or B _n HIGH or LOW)	5.0	3.0	9.5	12.0	2.5	13.0	ns	3-6
t _{PHL}	Propagation Delay SBA or SAB to A _n or B _n (w/A _n or B _n HIGH or LOW)	5.0	3.0	9.5	12.0	2.5	13.0	ns	3-6
t _{PZH}	Enable Time G̅ to A _n or B _n	5.0	2.0	9.0	11.0	1.5	12.0	ns	3-7
t _{PZL}	Enable Time G̅ to A _n or B _n	5.0	3.5	9.0	11.0	3.0	12.0	ns	3-8
t _{PHZ}	Disable Time G̅ to A _n or B _n	5.0	5.0	10.5	13.0	4.5	14.5	ns	3-7
t _{PLZ}	Disable Time G̅ to A _n or B _n	5.0	3.5	10.0	12.5	3.0	14.0	ns	3-8
t _{PZH}	Enable Time DIR to A _n or B _n	5.0	2.0	6.5	12.5	1.5	13.5	ns	3-7
t _{PZL}	Enable Time DIR to A _n or B _n	5.0	3.5	6.5	12.5	3.0	13.5	ns	3-8
t _{PHZ}	Disable Time DIR to A _n or B _n	5.0	5.0	8.5	12.5	4.5	13.5	ns	3-7
t _{PLZ}	Disable Time DIR to A _n or B _n	5.0	3.5	8.5	12.5	3.0	13.5	ns	3-8

*Voltage Range 5.0 V is 5.0 V ±0.5 V.

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AC OPERATING REQUIREMENTS

Symbol	Parameter	V _{CC} * (V)	74ACT		74ACT	Unit	Fig. No.
			T _A = +25°C C _L = 50 pF		T _A = -40°C to +85°C C _L = 50 pF		
			Typ	Guaranteed Minimum			
t _s	Setup Time, HIGH or LOW Bus to Clock	5.0	–	7.0	8.0	ns	3–9
t _h	Hold Time, HIGH or LOW Bus to Clock	5.0	–	2.5	2.5	ns	3–9
t _w	Clock Pulse Width HIGH or LOW	5.0	–	7.0	8.0	ns	3–6

*Voltage Range 5.0 V is 5.0 V ±0.5 V.

CAPACITANCE

Symbol	Parameter	Value Typ	Unit	Test Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = 5.0 V
C _{I/O}	Input/Output Capacitance	15	pF	V _{CC} = 5.0 V
C _{PD}	Power Dissipation Capacitance	60	pF	V _{CC} = 5.0 V

ORDERING INFORMATION

Device	Package	Shipping [†]
MC74AC646DWR2G	SOIC–24 (Pb–Free)	1000 / Tape & Reel
MC74ACT646DWG		30 Units / Rail
MC74ACT646DWR2G		1000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

